

# MPFF300R17MBF 1700V300A IGBT Module

#### **Electrical Features**

- Trench/Fieldstop IGBT
- Low Vce(sat)
- Vce(sat) with positive temperature coefficient
- $10 \ \mu \ s$  short circuit capability
- Fast&soft reverse recovery anti-parallel FWD
- Low inductance case

## **Typical Applications**

- Motor Drives
- High Power Converters
- UPS System
- Servo Drives
- Wind Turbines

#### IGBT, Inverter

Maximun	1 Rated Values								
Symbol	Item	Conditions			Rating		Unit		
IGBT									
V <sub>CES</sub>	Collector-emitter voltage	T <sub>vj</sub> =25°C			1700		V		
V <sub>GES</sub>	Gate-emitter voltage	-			±20		V		
Ic	Collector current,DC	T <sub>C</sub> =100°C,T <sub>vj</sub> =175°	С		300		А		
I <sub>CRM</sub>	Repetitive peak collector current	t <sub>p</sub> =1ms			600		А		
P <sub>tot</sub>	Total power dissipation	T <sub>C</sub> =25°C,T <sub>vj</sub> =175°C				W			
Characteristics Values									
Symbol	Item	Conditions			Values		Unit		
IGBT				Min.	Тур.	Max.			
I <sub>CES</sub>	Collector-emitter cut-off current	V <sub>CE</sub> =1700V,V <sub>GE</sub> =0V,T <sub>vj</sub> =25°C		-	-	3	mA		
I <sub>GES</sub>	Gate leakage current	V <sub>CE</sub> =0V,V <sub>GE</sub> =20V,T <sub>vj</sub> =25°C			-	400	nA		
$V_{\text{GE(th)}}$	Gate-emitter threshold voltage	I <sub>C</sub> =9mA,V <sub>CE</sub> =V <sub>GE</sub> ,T	5.2	5.5	6.4				
		I -200 A	T <sub>vj</sub> =25°C	-	2.17	3.6	V		
V <sub>CEsat</sub>	Collector-emitter saturation voltage	$I_{\rm C}$ -500A	T <sub>vj</sub> =125°C	-	2.68	-	v		
		V GE-13 V	T <sub>vj</sub> =150°C	-		-			
Cies	Input capacitance	$V_{CE}=25V, V_{GE}=0V$		-	41.6	-	тE		
Cres	Reverse transfer capacitance	f=1MHz,T <sub>vj</sub> =25°C		-	1.25	-	ΠГ		
Q <sub>G</sub>	Gate charge	$V_{GE} = -15V+15V$		-	3.69	-	μC		
Rg	Internal gate resistance	T <sub>vj</sub> =25°C			1.61		Ω		



			T <sub>vj</sub> =25°C	-	384	-	
t <sub>d(on)</sub>	Turn-on delay time		T <sub>vj</sub> =125°C	-	389	-	
			T <sub>vj</sub> =150°C	-		-	
		V <sub>CC</sub> =900V,	T <sub>vj</sub> =25°C	-	178	-	
t <sub>r</sub>	Rise time	I <sub>C</sub> =300A,	T <sub>vj</sub> =125°C	-	187	-	
		$V_{GE}=\pm 15V$ ,	T <sub>vj</sub> =150°C	-		-	
		$R_{G(on)}=2.4 \Omega$ ,	T <sub>vj</sub> =25°C	-	623	-	115
$t_{d(off)}$	Turn-off delay time	$R_{G(off)}=2.4 \Omega$ ,	T <sub>vj</sub> =125°C	-	699	-	
		Inductive load	T <sub>vj</sub> =150°C	-		-	
			T <sub>vj</sub> =25°C	-	558	-	
$t_{\mathrm{f}}$	Fall time		$T_{vj}=125^{\circ}C$	-	801	-	
			T <sub>vj</sub> =150°C	-		-	
		V <sub>CC</sub> =900V,I <sub>C</sub> =300 A,	T <sub>vj</sub> =25°C	-	145.4	-	
Eon	Turn-on energy (per pulse)	$V_{GE}=\pm 15V$ ,	T <sub>vj</sub> =125°C	-	190.3	-	
		$R_{G(on)}=2.4 \Omega,$ $R_{G(off)}=2.4 \Omega,$	T <sub>vj</sub> =150°C	-		-	
		$di/dt=4525A/\mu s(T_{vj}=$	T <sub>vj</sub> =25°C	-	124.9	-	mJ
$E_{\text{off}}$	Turn-off energy (per pulse)	$du/dt=6740V/\mu s(T_{vj}=$	T <sub>vj</sub> =125°C	-	160.7	-	
		25°C)	T <sub>vj</sub> =150°C	-		-	
SC data	Short-circuit current	$V_{CC}=900V, V_{GE} \le 15V, 7$	Г <sub>vj</sub> =25°С,				А
	Thermal register as investion to	t⊵≤10µs					
$R_{thJC} \\$	case	per IGBT		-			K/W
$R_{th\rm CH}$	Thermalresistance, case to heatsink	per IGBT/ λgrease=1	W/(m·K)	-		-	K/W
$T_{vjop}$	Temperature under switching condit	tions -40		-40		150	°C
Diode, In	nverter						
Maximun	n Rated Values						
Symbol	Item	Cond	litions		Rat	ing	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage	$T_{vj}=25^{\circ}C$			1700		V
$I_{\rm F}$	Forward current,DC				300		А
I <sub>FRM</sub>	Repetitive peak forward current	t <sub>p</sub> =1ms			60	)0	А
Characte	ristic Values			Min.	Тур.	Max.	
		I	T <sub>vj</sub> =25°C	-	2.1	3.0	
$V_{\mathrm{F}}$	Continuous forward voltage	$V_{cr}=0V$	T <sub>vj</sub> =125°C	-	2.0	-	V
		V GE O V	T <sub>vj</sub> =150°C	-		-	
I <sub>RM</sub>	Peak reverse recovery current	$V_{R}=900V$ $I_{F}=300A$ $V_{OR}=-15V$	T <sub>vj</sub> =25°C	-	223	-	А
			T <sub>vj</sub> =125°C	-	329	-	
			T <sub>vj</sub> =150°C	-		-	
t <sub>rr</sub> R		$V_{GE}$ -13V - $di_F/dt$ =4096A/µs ( $T_{vj}$ =25°C)	T <sub>vj</sub> =25°C	-	701	-	
	Reverse recovery time		T <sub>vj</sub> =125°C	-	922	-	ns
			T <sub>vj</sub> =150°C	-		-	

		V -000V	T <sub>vj</sub> =25°C	-	49	-	
$Q_r$	Recovered charge	$V_{\rm R} = 900 V$	T <sub>vj</sub> =125°C	-	128	-	μC
E <sub>rec</sub>	Reverse recovered energy	$V_{r} = 15V$	T <sub>vj</sub> =150°C	-		-	
		$v_{GE}$ -13v -di <sub>F</sub> /dt=4096A/ $\mu$ s (T <sub>vj</sub> =25°C)	T <sub>vj</sub> =25°C	-	32.1	-	
			T <sub>vj</sub> =125°C	-	71.6	-	mJ
			T <sub>vj</sub> =150°C	-		-	
р	Thermal resistance, junction to	ner diode					K/W
<b>R</b> thJC	case			-			K/ W
$R_{\mathrm{thCH}}$	Thermalresistance, case to	per diada/) grassa= $1W/(m \cdot K)$	m·K)	_		_	K/W
	heatsink	per diode/ xgrease=1 w/(iii'K)		-		-	IX/ W
$T_{vjop}$	Temperature under switching con	g conditions		-40		150	°C

## **NTC Thermistor Characteristics**

Symphol	Item	Conditions	Values			Unit
Symbol		Conditions	Min.	Тур.	Max.	
R <sub>25</sub>	Rated resistance	$T_{C}=25^{\circ}C$	-	5	-	kΩ
$\Delta R/R$	Deviation of resistance	$T_{C}=100^{\circ}C, R_{100}=493\Omega$	-5	-	5	%
P <sub>25</sub>	Power dissipation	$T_{\rm C}=25^{\circ}{\rm C}$	-	-	20	mW
B <sub>25/50</sub>	B-constant	$R_2 = R_{25} exp[B_{25/50}(1/T_2-1/(298.15K))]$	-	3375	-	
B <sub>25/80</sub>	B-constant	$R_2 = R_{25} exp[B_{25/80}(1/T_2-1/(298.15K))]$	-	3411	-	Κ
B <sub>25/100</sub>	B-constant	$R_2 = R_{25} exp[B_{25/100}(1/T_2-1/(298.15K))]$	_	3433	-	

## Module

Symbol	Item	Conditions	Rating		Unit	
V <sub>ISOL</sub>	Isolation voltage	Terminals to baseplate, RMS,f=50Hz,t=1min	4000			V
-	Material of module baseplate	-	Cu			-
-	Internal isolation	Basic insulation(class 1, IEC 61140)	Al <sub>2</sub> O <sub>3</sub>			-
T <sub>stg</sub>	Storage temperature	-	-40~125			°C
Coursels a 1	Item	Conditions	Values			Unit
Symbol		Conditions	Min.	Тур.	Max.	
М	Mounting torque for module mounting	Screw M5	3.0	-	5.0	Nm
	Terminal connection torque	Screw M6	2.5	-	5.0	Nm
4	Crosmaga distance	Terminal to terminal	-	13	-	100.000
UCreep	Creepage distance	Terminal to base plate	-	14.5	-	шш
$d_{\mathrm{Clear}}$	Clearance	Terminal to terminal	-	10	-	
		Terminal to base plate	-	12.5	-	m
m	Weight	-		348	-	g

#### Circuit diagram headline



## Package outlines (Unit: mm)











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item	Date	Change History Description	Rev. item	Responsibility	
1	2023.9.9	初版规格书发布,版本为V1.0	2023 9 Ver1.0	梁华文	
2	2023.10.19	更新外形图,变更为V1.1版本	2023 10 Ver1.1	梁华文	